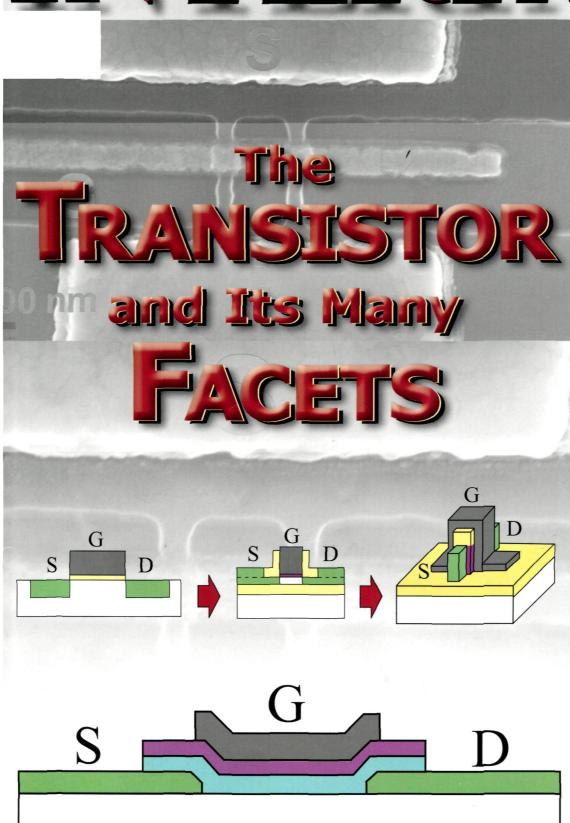
The Electrochemical Society

INTERFACE



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On the cover...

The figures used in the cover illustration reflect the diversity of field-effect transistor architectures by showing the evolution of the MOSFET, a simplified cross-section of a Thin Film Transistor (TFT), and a SEM image of the Multi-Gate FET (MUGFET).

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